ABSTRACT

this study is to search for novel The of aim semiconductor materials for photoelectrochemical cells devices. photocatalytic The diffuse reflectance and measurements, flat band potential measurements, photocurrent behaviour and conductivity properties were used to identify and characterize these materials.

Tt was found that cuprous thiocyanate shows relatively high photostability and possibility of sensitization with visible light. Another advantage of this material is that thin layers can be deposited on copper surface. The thin layer of p-CuCNS supresses photocorrosion of the Cu₂0 photocathode in aqueous Catalytic properties of thiocyanate. The CuCNS was β -form of p-CuCNS was found to also studied. The photooxide water in the presence of sacrificial agents.

In addition, colloidal suspensions, surface modified catalysts and composite catalysts were tested for their photocatalytic activity in nitrogen fixation.

Among them, the following systems showed relatively high activity. (1) Pt, Ag, Hg coated $SrTiO_3$, (2) Hydrated ferric oxide, (3) Composite catalyst of Ti(IV) exchanged ferric oxide, (4) Hydrous cuprous oxide and (5) Cuprous chloride coated hydrous cuprous oxide. The high activity of these materials is due to good charge separation, strong negative flat band potentials and chemisorption of N₂.